April 2007

FAIRCHILD

SEMICONDUCTOR

FFP08H60S Hyperfast 2 Rectifier

Features

- High Speed Switching (t_{rr}=45ns(Max.) @ I_F=8A)
- High Reverse Voltage and High Reliability
- Avalanche Energy Rated
- Low Forward Voltage(V_F=2.1V(Max.) @ I_F=8A)

Applications

- General Purpose
- Switching Mode Power Supply
- Free-wheeling diode for motor application
- Power switching circuits

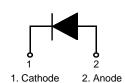
8A, 600V Hyperfast 2 Rectifier

The FFP08H60S is hyperfast2 rectifier ($t_{rr}{=}45ns(Max.)$ @ $l_{F}{=}8A$). it has half the recovery time of ultrafast rectifier and is silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as freewheeling/clamping rectifiers in a variety of switching power supplies and other power switching applications. Its low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

Pin Assignments





741040

Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V _{RRM}	Peak Repetitive Reverse Voltage	600	V	
V _{RWM}	Working Peak Reverse Voltage	600	V	
V _R	DC Blocking Voltage	600	V	
I _{F(AV)}	Average Rectified Forward Current @ $T_C = 105 \ ^{\circ}C$	8	А	
I _{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	60	A	
T _{J,} T _{STG}	Operating Junction and Storage Temperature	- 65 to +150	°C	

Thermal Characteristics T_c = 25[°]C unless otherwise noted

Symbol	Parameter	Мах	Units
R_{\thetaJC}	Maximum Thermal Resistance, Junction to Case	2.5	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
08H60S	FFP08H60STU	TO-220	-	-	50

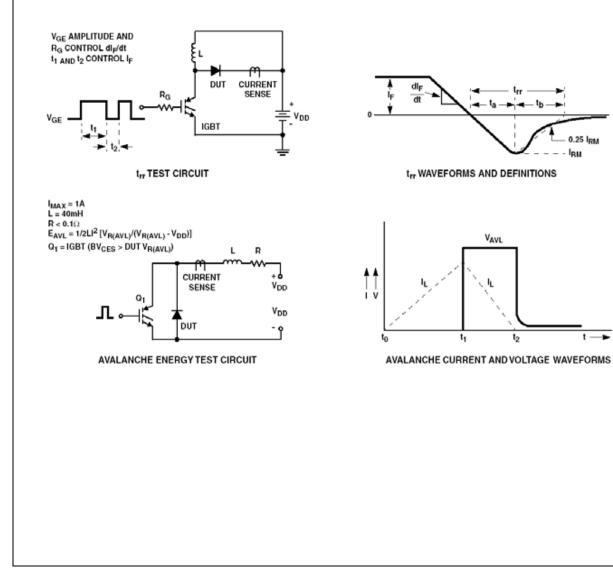
FFP08H60S Hyperfast 2 Rectifier

Parameter	Conditions			Тур.	Max	Units
V _{FM} ¹	I _F = 8A I _F = 8A	T _C = 25 °C T _C = 125 °C	-	-	2.1 1.7	V V
I _{RM} ¹	$V_{R} = 600V$ $V_{R} = 600V$	T _C = 25 °C T _C = 125 °C	-	-	100 200	μΑ μΑ
t _{rr}	$I_{F} = 1A, di/dt = 100A/\mu s, V_{CC} = 30V$ $I_{F} = 8A, di/dt = 100A/\mu s, V_{CC} = 390V$	T _C = 25 °C T _C = 25 °C	-	-	35 45	ns ns
t _a t _b Q _{rr}	I _F =8A, di/dt = 100A/μs, V _{CC} = 390V	T _C = 25 °C T _C = 25 °C T _C = 25 °C T _C = 25 °C	- -	15 16 18.6		ns ns nC
W _{AVL}	Avalanche Energy (L = 40mH)		20	-	-	mJ

Notes:

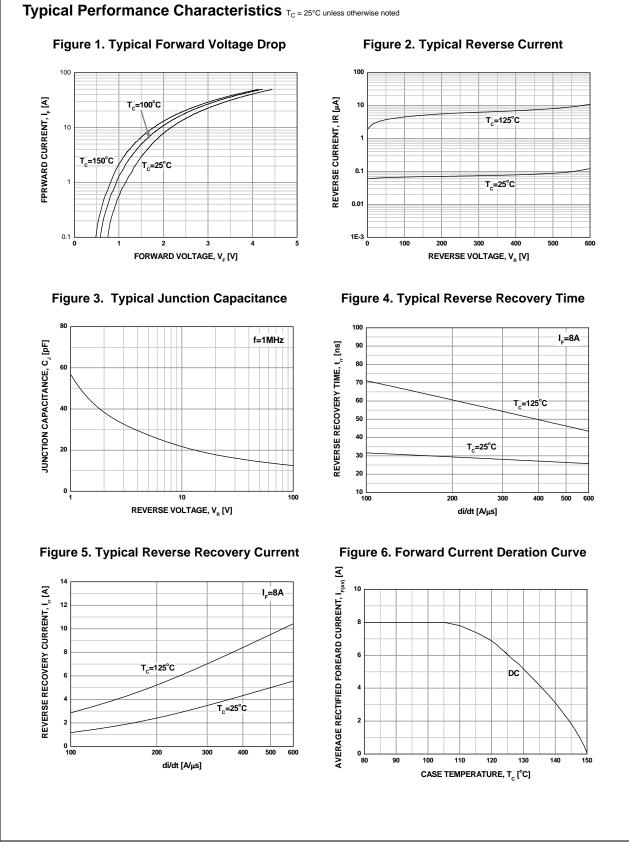
1. Pulse : Test Pulse width = 300μ s, Duty Cycle = 2%

Test Circuit and Waveforms



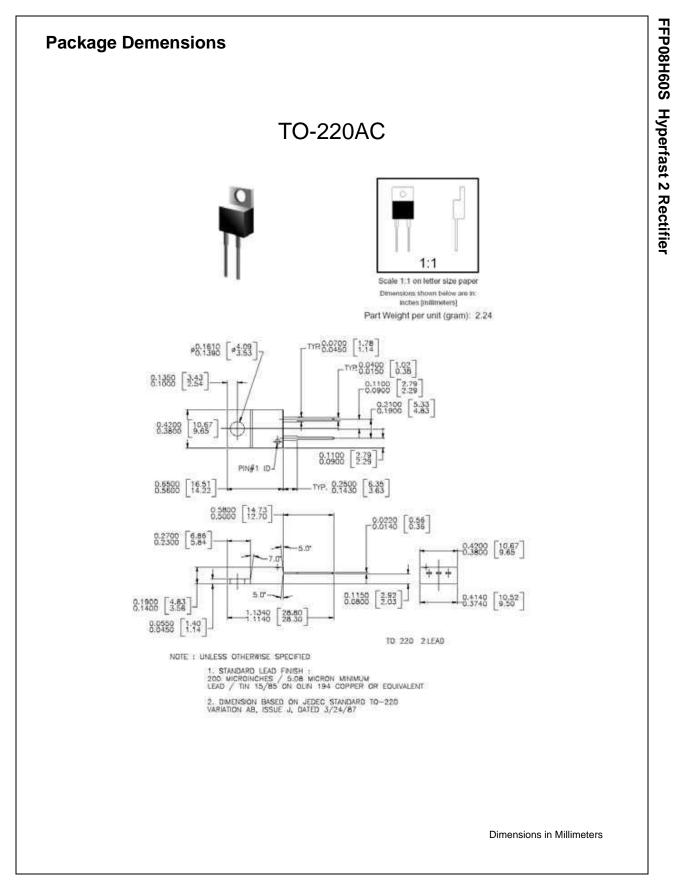
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FFP08H60S Hyperfast 2 Rectifier



FFP08H60S Rev. A

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Bottomless™	<i>i-Lo</i> ™	PowerTrench [®]	тм
Build it Now™	ImpliedDisconnect [™]	Programmable Active Droop™	U.
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